

Ballistic transport

$$\vec{F} = m\vec{a} = -e\vec{E} = m \frac{d\vec{v}}{dt}$$

$$\vec{v} = \frac{-e\vec{E}t}{m} + \vec{v}_0$$

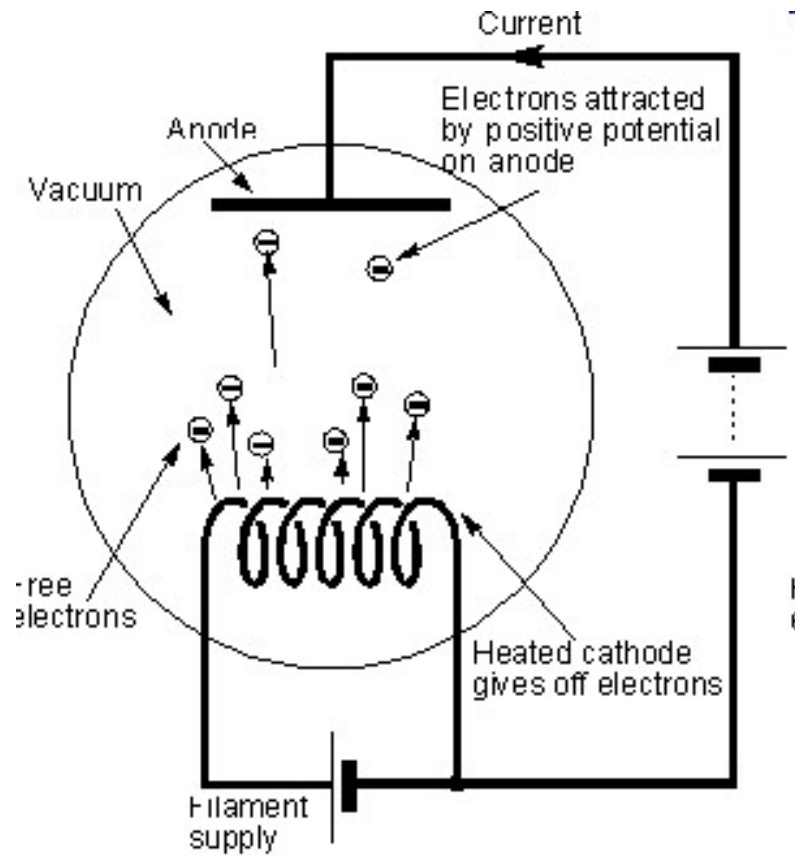
$$\vec{x} = \frac{-e\vec{E}t^2}{2m} + \vec{v}_0t + \vec{x}_0$$

electrons in an electric field follow a parabola.

electrons in a magnetic field move in a spiral

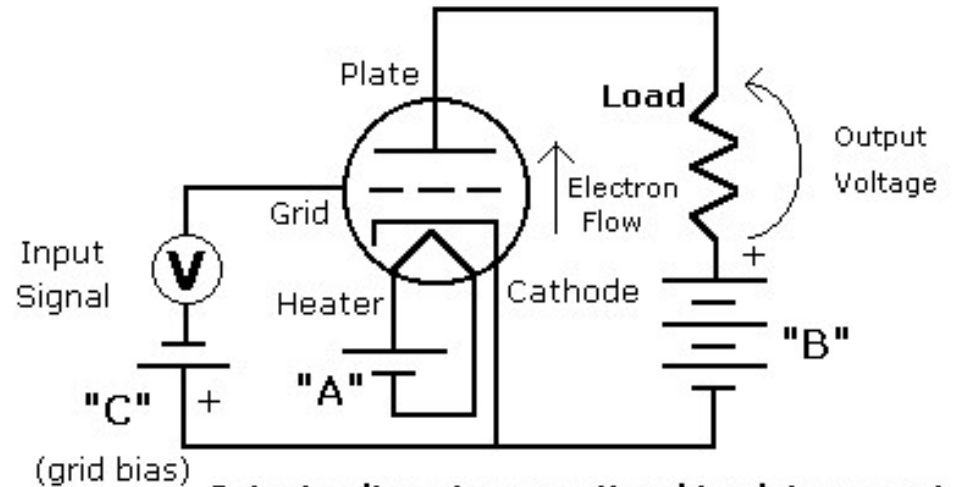
electrons crossed electric and magnetic fields spiral along the direction perpendicular to the electric and magnetic fields

Vacuum diodes



diode

The Common-cathode Triode Amplifier



Output voltage is proportional to plate current, which is controlled by grid voltage.



Diffusive transport

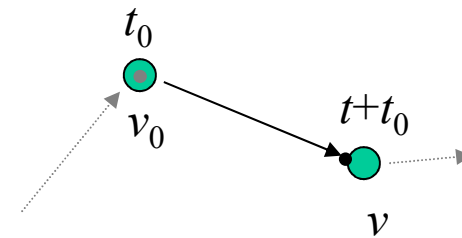
$$\vec{F} = -e\vec{E} = m^* \vec{a} = m^* \frac{d\vec{v}}{dt}$$

$$\vec{v} = \vec{v}_0 - \frac{e\vec{E}}{m^*} (t - t_0)$$

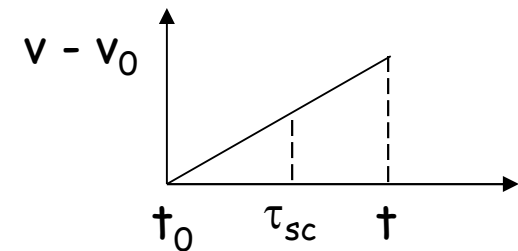
$$\langle v_0 \rangle = 0$$

$\langle t - t_0 \rangle = \tau_{sc}$ < average time between scattering events

time between two collisions



$$\vec{v}_d = \frac{-e\vec{E}\tau_{sc}}{m^*} = \frac{-e\vec{E}\ell}{m^* v_F}$$



drift velocity: $\vec{v}_d = -\mu\vec{E}$

Matthiessen's rule

$$\frac{1}{\tau_{sc}} = \frac{1}{\tau_{sc,lattice}} + \frac{1}{\tau_{sc,impurity}}$$

↑
phonons, temperature dependent

↑ mostly temperature independent

$$\frac{1}{\mu} = \frac{1}{\mu_{lattice}} + \frac{1}{\mu_{impurity}}$$

Ballistic transport in transistors

The mean free path ~ 100 nm $>$ gate length ~ 20 nm

v not proportional to E

~~$$\vec{v} = \mu \vec{E}$$~~

j not proportional to E

~~$$\vec{j} = \sigma \vec{E}$$~~

nonlocal response

Electrons bend in a magnetic field like they do in vacuum.

Magnetic field (diffusive regime)

$$\vec{F} = m\vec{a} = -e\vec{E} = m \frac{\vec{v}_d}{\tau_{sc}} \qquad -\frac{e\tau_{sc}}{m} \vec{E} = \vec{v}_d$$

$$\vec{F} = m\vec{a} = -e(\vec{E} + \vec{v} \times \vec{B}) = m \frac{\vec{v}_d}{\tau_{sc}}$$

If B is in the z -direction, the three components of the force are

$$-e(E_x + v_{dy}B_z) = m \frac{v_{dx}}{\tau_{sc}}$$

$$-e(E_y - v_{dx}B_z) = m \frac{v_{dy}}{\tau_{sc}}$$

$$-e(E_z) = m \frac{v_{dz}}{\tau_{sc}}$$

Magnetic field (diffusive regime)

$$v_{d,x} = -\frac{eE_x \tau_{sc}}{m} - \frac{eB_z}{m} \tau_{sc} v_{d,y}$$

$$v_{d,y} = -\frac{eE_y \tau_{sc}}{m} + \frac{eB_z}{m} \tau_{sc} v_{d,x}$$

$$v_{d,z} = -\frac{eE_z \tau_{sc}}{m}$$

If $E_y = 0$,

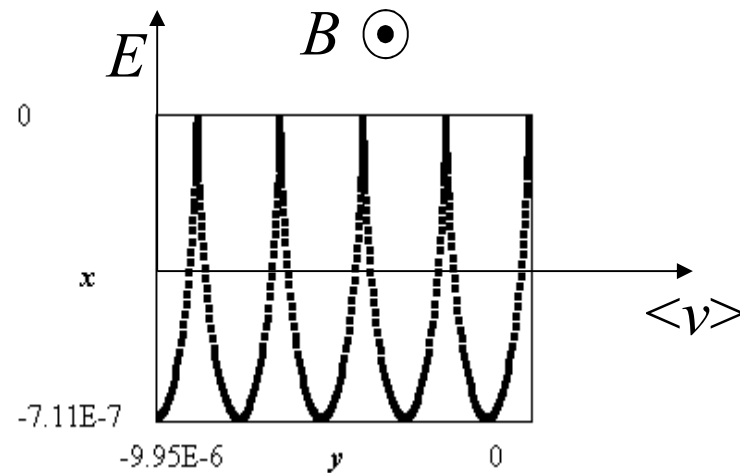
$$v_{d,y} = -\frac{eB_z}{m} \tau_{sc} v_{d,x}$$

$$\tan \theta_H = -\frac{eB_z}{m} \tau_{sc}$$

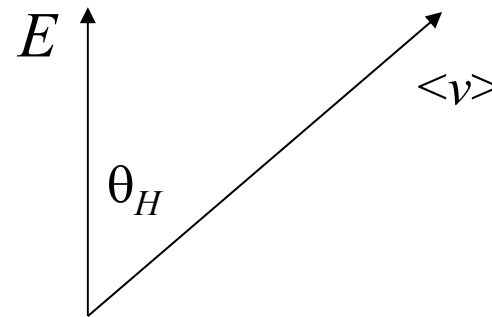
Crossed E and B fields

Ballistic transport

$$\vec{F} = m\vec{a} = -e(\vec{E} + \vec{v} \times \vec{B})$$

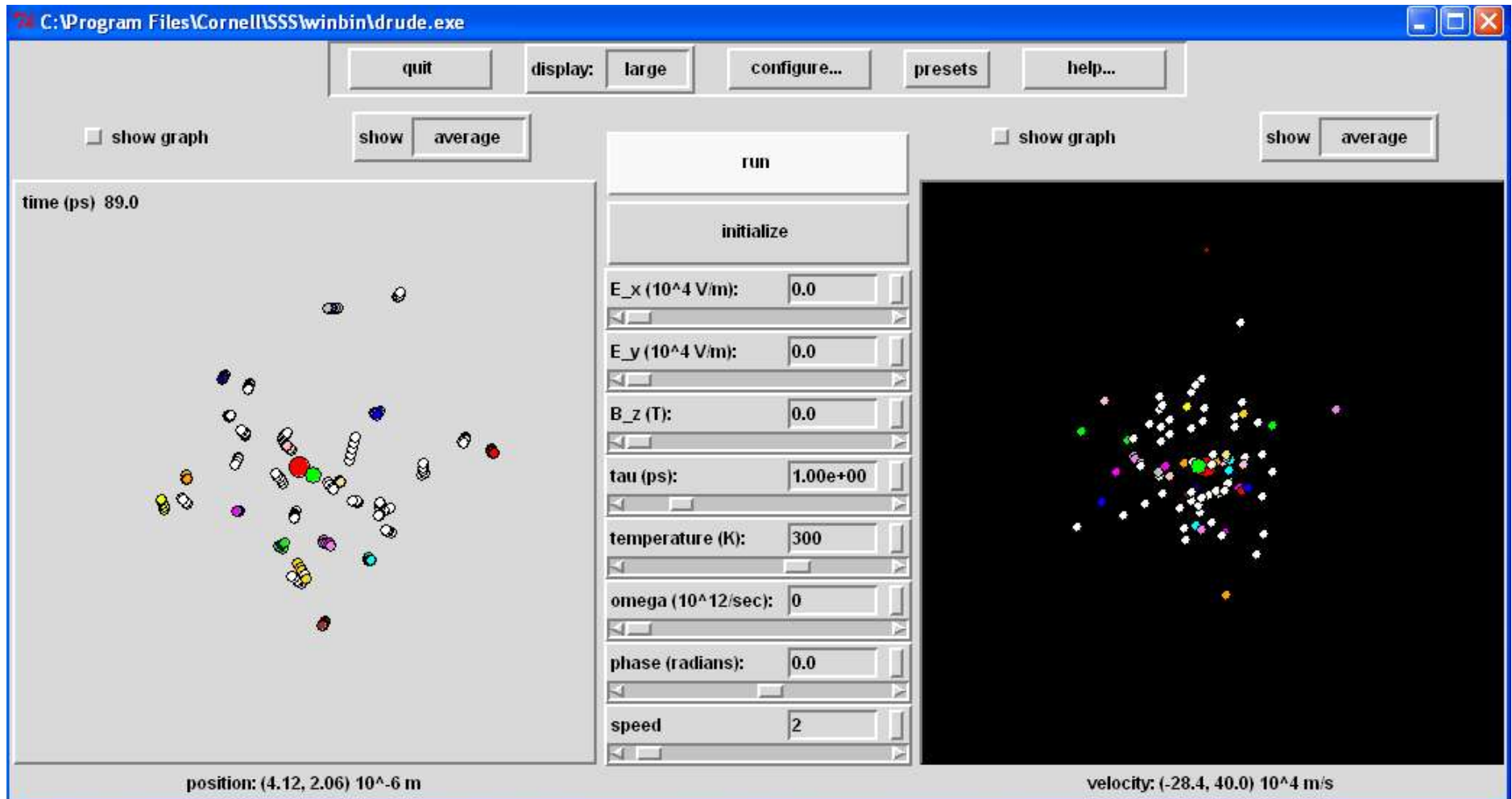


Diffusive transport



Hall angle:

$$\theta_H = \tan^{-1} \left(-\frac{eB_z \tau_{sc}}{m} \right)$$



If no forces are applied, the electrons diffuse.
 The average velocity moves against an electric field.
 In just a magnetic field, the average velocity is zero.
 In an electric and magnetic field, the electrons move in a straight line at the Hall angle.

C:\Program Files\Cornell\SSS\winbin\sommer.exe

quit

display:

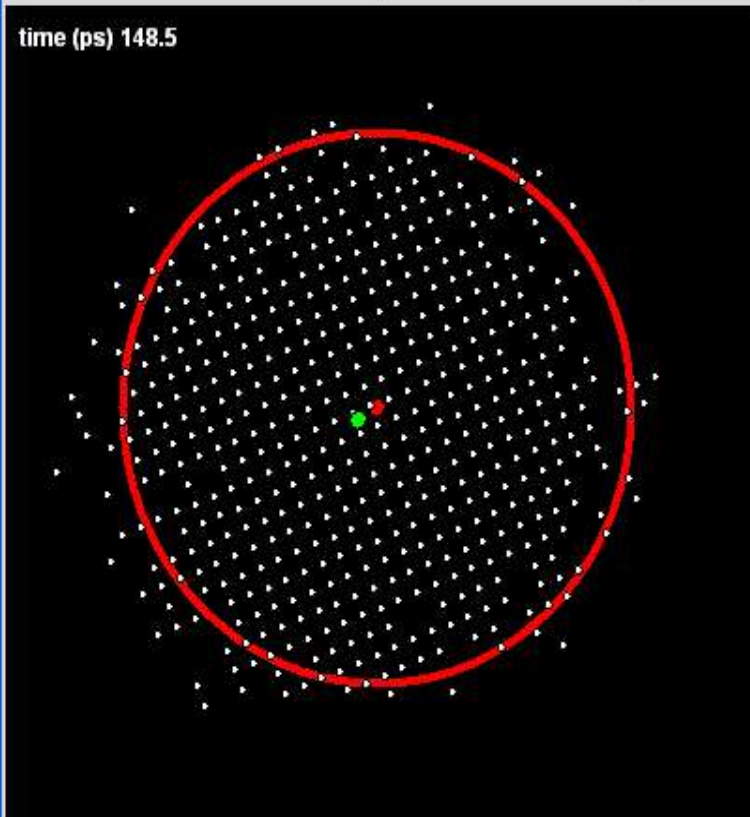
large

configure...

presets

help...

time (ps) 148.5



wave vector (1.88, -1.48) 1/A

stop

initialize

E_x (10^6 V/m): 1

E_y (10^6 V/m): 0

B_z (T): 0.9

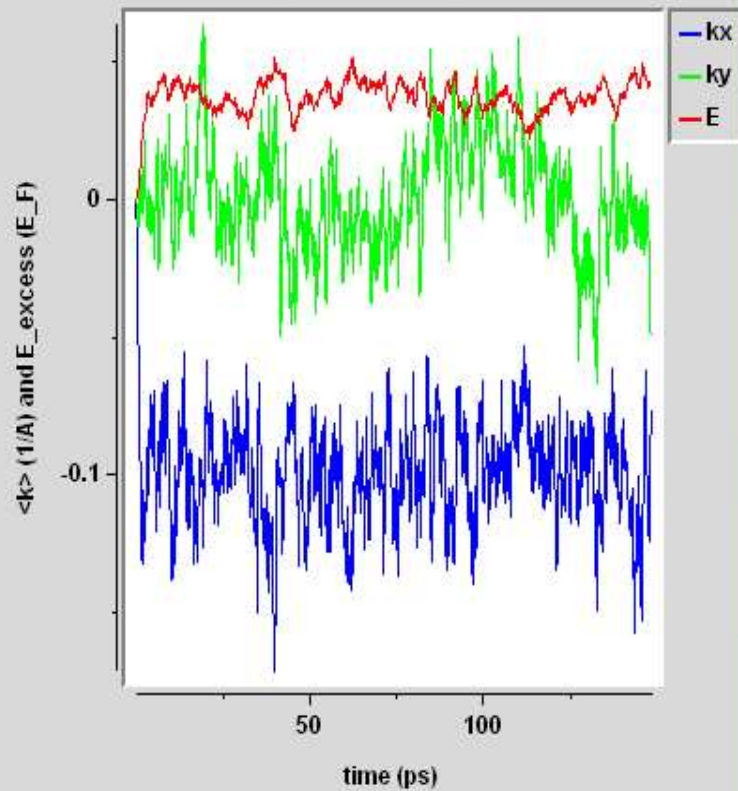
tau_i (ps): 1.00e+00

tau_e (ps): 1.00e+04

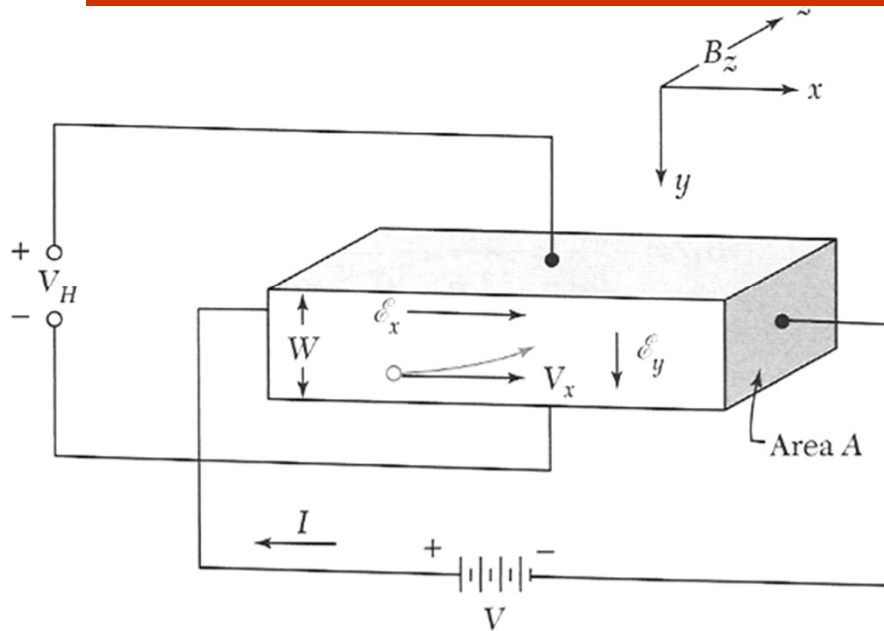
E_Fermi (eV): 7

speed 1

copy graph



The Hall Effect (diffusive regime)



$$v_{d,x} = -\frac{eE_x \tau_{sc}}{m} - \frac{eB_z}{m} \tau_{sc} v_{d,y}$$

$$v_{d,y} = -\frac{eE_y \tau_{sc}}{m} + \frac{eB_z}{m} \tau_{sc} v_{d,x}$$

$$v_{d,z} = -\frac{eE_z \tau_{sc}}{m}$$

If $v_{d,y} = 0$,

$$E_y = v_{d,x} B_z = V_H / W = R_H j_x B_z \quad V_H = \text{Hall voltage}, R_H = \text{Hall Constant}$$

$$v_{d,x} = -j_x / ne$$

$$R_H = E_y / j_x B_z = -1/ne$$

Metal	Method	Experimental R_H , in 10^{-24} CGS units	Assumed carriers per atom	Calculated $-1/nec$, in 10^{-24} CGS units
Li	conv.	-1.89	1 electron	-1.48
Na	helicon	-2.619	1 electron	-2.603
	conv.	-2.3		
K	helicon	-4.946	1 electron	-4.944
	conv.	-4.7		
Rb	conv.	-5.6	1 electron	-6.04
Cu	conv.	-0.6	1 electron	-0.82
Ag	conv.	-1.0	1 electron	-1.19
Au	conv.	-0.8	1 electron	-1.18
Be	conv.	+2.7	—	—
Mg	conv.	-0.92	—	—
Al	helicon	+1.136	1 hole	+1.135
In	helicon	+1.774	1 hole	+1.780
As	conv.	+50.	—	—
Sb	conv.	-22.	—	—
Bi	conv.	-6000.	—	—

Diffusion equation/ heat equation

Diffusion constant $\frac{dn}{dt} = -D\nabla^2 n$

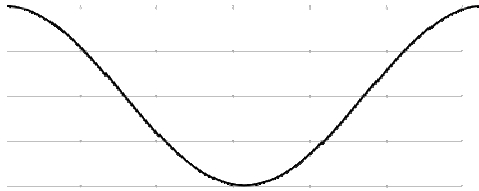
Fick's law $\vec{j} = -D\nabla n$

Continuity equation $\frac{dn}{dt} = \nabla \cdot \vec{j}$



$$n = \frac{1}{\sqrt{4\pi Dt}} \exp\left(\frac{-r^2}{4Dt}\right)$$

Einstein relation



$$\vec{F} = -\nabla U_{pot} = -e\vec{E}$$

$$n(x) = A \exp\left(\frac{-U_{pot}(x)}{k_B T}\right) \text{ Boltzmann factor}$$

In equilibrium, drift = diffusion

$$en\mu\vec{E} + eD\nabla n = 0$$

$$\nabla n = -\frac{1}{k_B T} A \exp\left(\frac{-U_{pot}}{k_B T}\right) \nabla U_{pot} = -\frac{n}{k_B T} \nabla U_{pot} = \frac{-en\vec{E}}{k_B T}$$

$$en\mu\vec{E} - e^2 D \frac{n\vec{E}}{k_B T} = 0$$

$$D = \frac{\mu k_B T}{e}$$

Über die von der molekularkinetischen Theorie der Wärme geforderte Bewegung von in ruhenden Flüssigkeiten suspendierten Teilchen, A. Einstein (1905).

Thermal conductivity

$$\vec{j}_U = \bar{E} \vec{j}$$

Average particle energy

$$u = \bar{E} n$$

internal energy density

$$\vec{j}_U = -\bar{E} D \nabla n = -D \nabla u$$

$$\vec{j}_U = -D \frac{du}{dT} \nabla T = -D c_v \nabla T$$

$$\vec{j}_U = -K \nabla T$$

Thermal conductivity

$$K = D c_v$$

$$K \rightarrow 0 \quad \text{as} \quad T \rightarrow 0$$

Wiedemann - Franz law

$$\frac{K}{\sigma} = \frac{Dc_v}{ne\mu}$$

Einstein relation: $D = \frac{\mu k_B T}{e}$

Dulong - Petit: $c_v = 3nk_B$

$$\frac{K}{\sigma} = \frac{3k_B^2}{e^2} T$$

Wiedemann Franz law

$$L = \frac{K_{el}}{\sigma T} = 2.22 \times 10^{-8} \quad \text{W } \Omega / \text{K}^2$$

Lorentz number



Lorenz number

$$L = \frac{K_{el}}{\sigma T} = 2.22 \times 10^{-8} \quad \text{W } \Omega / \text{K}^2$$

Table 5 Experimental Lorenz numbers

$L \times 10^8$ watt-ohm/deg ²			$L \times 10^8$ watt-ohm/deg ²		
Metal	0°C	100°C	Metal	0°C	100°C
Ag	2.31	2.37	Pb	2.47	2.56
Au	2.35	2.40	Pt	2.51	2.60
Cd	2.42	2.43	Su	2.52	2.49
Cu	2.23	2.33	W	3.04	3.20
Mo	2.61	2.79	Zn	2.31	2.33

At low temperatures the classical predictions for the thermal and electrical conductivities are too high but their ratio is correct. Only the electrons within $k_B T$ of the Fermi surface contribute.

Crystal Physics

Crystal physics explains what effects the symmetries of the crystal have on observable quantities.

An Introduction to Crystal Physics Ervin Hartmann

<http://ww1.iucr.org/comm/cteach/pamphlets/18/index.html>

International Tables for Crystallography

<http://it.iucr.org/>

Kittel chapter 3: elastic strain

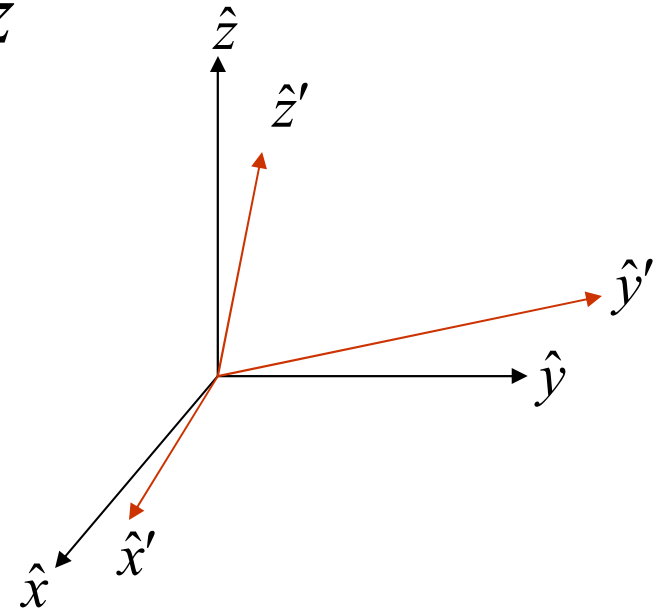
Strain

A distortion of a material is described by the strain matrix

$$x' = (1 + \varepsilon_{xx})\hat{x} + \varepsilon_{xy}\hat{y} + \varepsilon_{xz}\hat{z}$$

$$y' = \varepsilon_{yx}\hat{x} + (1 + \varepsilon_{yy})\hat{y} + \varepsilon_{yz}\hat{z}$$

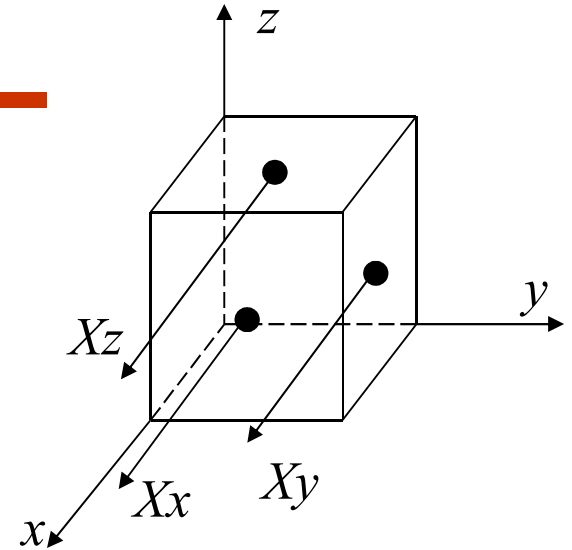
$$z' = \varepsilon_{zx}\hat{x} + \varepsilon_{zy}\hat{y} + (1 + \varepsilon_{zz})\hat{z}$$



Stress

9 forces describe the stress

$X_x, X_y, X_z, Y_x, Y_y, Y_z, Z_x, Z_y, Z_z$



X_x is a force applied in the x -direction to the plane normal to x

X_y is a shear force applied in the x -direction to the plane normal to y

stress tensor:

$$\sigma = \begin{bmatrix} \frac{X_x}{A_x} & \frac{X_y}{A_y} & \frac{X_z}{A_z} \\ \frac{Y_x}{A_x} & \frac{Y_y}{A_y} & \frac{Y_z}{A_z} \\ \frac{Z_x}{A_x} & \frac{Z_y}{A_y} & \frac{Z_z}{A_z} \end{bmatrix}$$

Stress is force/m²

Stress and Strain

$$\boldsymbol{\varepsilon}_{ij} = S_{ijkl} \boldsymbol{\sigma}_{kl}$$

The stress - strain relationship is described by a rank 4 stiffness tensor. The inverse of the stiffness tensor is the compliance tensor.

$$\boldsymbol{\sigma}_{ij} = C_{ijkl} \boldsymbol{\varepsilon}_{kl}$$

Einstein convention: sum over repeated indices.

$$\begin{aligned} \varepsilon_{xx} = & S_{xxxx} \sigma_{xx} + S_{xxxy} \sigma_{xy} + S_{xxxz} \sigma_{xz} + S_{xxyx} \sigma_{yx} + S_{xxyy} \sigma_{yy} \\ & + S_{xxyz} \sigma_{yz} + S_{xxzx} \sigma_{zx} + S_{xxzy} \sigma_{zy} + S_{xxzz} \sigma_{zz} \end{aligned}$$

Statistical Physics

Microcanonical Ensemble: Internal energy is expressed in terms of extrinsic quantities $U(S, M, P, \varepsilon, N, V)$.

$$dU = TdS + \sigma_{ij}d\varepsilon_{ij} + E_k dP_K + H_l dM_l$$

$$dU = \frac{\partial U}{\partial S} dS + \frac{\partial U}{\partial \varepsilon_{ij}} d\varepsilon_{ij} + \frac{\partial U}{\partial P_k} dP_K + \frac{\partial U}{\partial M_l} dM_l$$

The normal modes must be solved for in the presence of electric and magnetic fields (Advanced Solid State Physics course).

Statistical Physics

Microcanonical Ensemble: Internal energy is expressed in terms of extrinsic quantities $U(S, M, P, \varepsilon, N, V)$. $\varepsilon_{ij} \Rightarrow V \varepsilon_{ij}$

$$dU = \frac{\partial U}{\partial S} dS + \frac{\partial U}{\partial \varepsilon_{ij}} d\varepsilon_{ij} + \frac{\partial U}{\partial P_k} dP_k + \frac{\partial U}{\partial M_l} dM_l$$

$$dU = TdS + \sigma_{ij} d\varepsilon_{ij} + E_k dP_k + H_l dM_l$$

Canonical ensemble: At constant temperature, make a Legendre transformation to the Helmholtz free energy.

$$F = U - TS$$

$$F(V, T, N, M, P, \varepsilon)$$

Make a Legendre transformation to the Gibbs potential $G(T, H, E, \sigma)$

$$G = U - TS - \sigma_{ij} \varepsilon_{ij} - E_k P_k - H_l M_l$$

Gibbs free energy

$$G = U - TS - \sigma_{ij}\varepsilon_{ij} - E_k P_k - H_l M_l$$

$$dG = dU - TdS - SdT - \sigma_{ij}d\varepsilon_{ij} - \varepsilon_{ij}d\sigma_{ij} - E_k dP_k - P_k dE_k - H_l dM_l - M_l dH_l$$

$$dU = TdS + \sigma_{ij}d\varepsilon_{ij} + E_k dP_k + H_l dM_l$$

$$dG = -SdT - \varepsilon_{ij}d\sigma_{ij} - P_k dE_k - M_l dH_l$$

$$\text{total derivative: } dG = \left(\frac{\partial G}{\partial T}\right)dT + \left(\frac{\partial G}{\partial \sigma_{ij}}\right)d\sigma_{ij} + \left(\frac{\partial G}{\partial E_k}\right)dE_k + \left(\frac{\partial G}{\partial H_l}\right)dH_l$$

$$\left(\frac{\partial G}{\partial \sigma_{ij}}\right) = -\varepsilon_{ij} \quad \left(\frac{\partial G}{\partial E_k}\right) = -P_k$$

$$\left(\frac{\partial G}{\partial H_l}\right) = -M_l \quad \left(\frac{\partial G}{\partial T}\right) = -S$$

$$\begin{aligned}
d\epsilon_{ij} &= \left(\frac{\partial \epsilon_{ij}}{\partial \sigma_{kl}}\right) d\sigma_{kl} + \left(\frac{\partial \epsilon_{ij}}{\partial E_k}\right) dE_k + \left(\frac{\partial \epsilon_{ij}}{\partial H_l}\right) dH_l + \left(\frac{\partial \epsilon_{ij}}{\partial T}\right) dT \\
dP_i &= \left(\frac{\partial P_i}{\partial \sigma_{kl}}\right) d\sigma_{kl} + \left(\frac{\partial P_i}{\partial E_k}\right) dE_k + \left(\frac{\partial P_i}{\partial H_l}\right) dH_l + \left(\frac{\partial P_i}{\partial T}\right) dT \\
dM_i &= \left(\frac{\partial M_i}{\partial \sigma_{kl}}\right) d\sigma_{kl} + \left(\frac{\partial M_i}{\partial E_k}\right) dE_k + \left(\frac{\partial M_i}{\partial H_l}\right) dH_l + \left(\frac{\partial M_i}{\partial T}\right) dT \\
dS &= \left(\frac{\partial S}{\partial \sigma_{kl}}\right) d\sigma_{kl} + \left(\frac{\partial S}{\partial E_k}\right) dE_k + \left(\frac{\partial S}{\partial H_l}\right) dH_l + \left(\frac{\partial S}{\partial T}\right) dT
\end{aligned}$$

1. Elastic deformation.
2. Reciprocal (or converse) piezo-electric effect.
3. Reciprocal (or converse) piezo-magnetic effect.
4. Thermal dilatation.
5. Piezo-electric effect.
6. Electric polarization.
7. Magneto-electric polarization.
8. Pyroelectricity.
9. Piezo-magnetic effect.
10. Reciprocal (or converse) magneto-electric polarization.
11. Magnetic polarization.
12. Pyromagnetism.
13. Piezo-caloric effect.
14. Electro-caloric effect.
15. Magneto-caloric effect.
16. Heat transmission.